TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π-MOSII⁻⁵)

2SK1930

Chopper Regulator, DC-DC Converter, and Motor Drive Applications

 $\begin{array}{ll} \bullet & Low\ drain-source\ ON\ resistance & \vdots\ R_{DS}\ (ON)=3.0\ \Omega\ (typ.) \\ \bullet & High\ forward\ transfer\ admittance & \vdots\ |Y_{fs}|=2.0\ S\ (typ.) \\ \bullet & Low\ leakage\ current & \vdots\ I_{DSS}=300\ \mu A\ (max)\ (V_{DS}=800\ V) \\ \bullet & Enhancement-mode & \vdots\ V_{th}=1.5{\sim}3.5\ V\ (V_{DS}=10\ V,\ I_{D}=1\ mA) \\ \end{array}$

Maximum Ratings (Ta = 25°C)

Characteris	stics	Symbol	Rating	Unit	
Drain-source voltage		V_{DSS}	1000	V	
Drain-gate voltage (R _{GS} = 20 kΩ)		V_{DGR}	1000	V	
Gate-source voltage		V_{GSS}	±20	V	
Drain current	DC (Note 1)	I _D	4	Α	
	Pulse (Note 1)	I _{DP}	12	А	
Drain power dissipation (Tc = 25°C)		P_{D}	80	W	
Channel temperature		T _{ch}	150	°C	
Storage temperature range		T _{stg}	-55~150	°C	

Thermal Characteristics

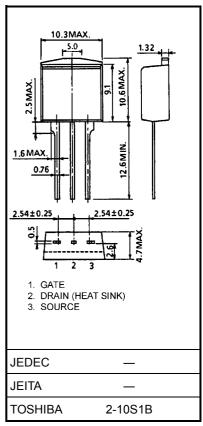
Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R _{th (ch-c)}	1.56	°C/W
Thermal resistance, channel to ambient	R _{th (ch-a)}	83.3	°C/W

Note 1: Please use devices on condition that the channel temperature is below 150°C.

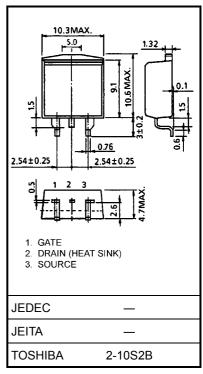
This transistor is an electrostatic sensitive device.

Please handle with caution.

Unit: mm



Weight: 1.5 g (typ.)



Weight: 1.5 g (typ.)

Electrical Characteristics (Ta = 25°C)

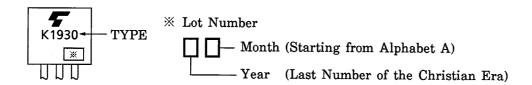
Charac	teristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cu	rrent	I _{GSS}	V _{GS} = ±20 V, V _{DS} = 0 V	_	_	±100	nA
Drain cut-off cur	rent	I _{DSS}	V _{DS} = 800 V, V _{GS} = 0 V	_	_	300	μΑ
Drain-source brovoltage	eakdown	V _{(BR) DSS}	I _D = 10 mA, V _{GS} = 0 V	1000	_	_	V
Gate threshold v	oltage	V_{th}	V _{DS} = 10 V, I _D = 1 mA	1.5	_	3.5	V
Drain-source Of	N resistance	R _{DS (ON)}	V _{GS} = 10 V, I _D = 2 A	_	3.0	3.8	Ω
Forward transfer	admittance	Y _{fs}	V _{DS} = 20 V, I _D = 2 A	1.0	2.0	_	S
Input capacitanc	е	C _{iss}		_	700	_	
Reverse transfer capacitance		C _{rss}	V _{DS} = 25 V, V _{GS} = 0 V, f = 1 MHz	_	55	_	pF
Output capacitance		Coss		_	100	_	
Switching time	Rise time	t _r	V_{GS} V_{OV} V_{DD} V_{OUT} V_{DD} V_{DD}	_	18	_	- ns
	Turn-on time	t _{on}		_	30	_	
	Fall time	t _f		_	12	_	
	Turn-off time	t _{off}	Duty $\leq 1\%$, $t_{\mathbf{W}} = 10 \mu \text{s}$	_	70	_	
Total gate charge (Gate-source plus gate-drain)		Qg		_	60	_	nC
Gate-source charge		Q _{gs}	$V_{DD} \approx 400 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 4 \text{ A}$	_	35	_	
Gate-drain ("miller") charge		Q _{gd}			25	_	

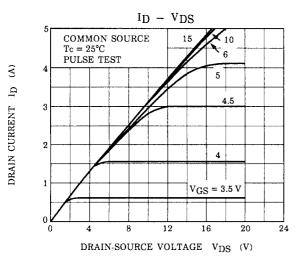
Source-Drain Ratings and Characteristics (Ta = 25°C)

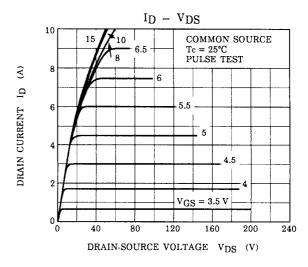
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I _{DR}	_	_	_	4	Α
Pulse drain reverse current (Note 1)	I _{DRP}	_	_	_	12	А
Forward voltage (diode)	V_{DSF}	I _{DR} = 4 A, V _{GS} = 0 V	_		-1.9	V

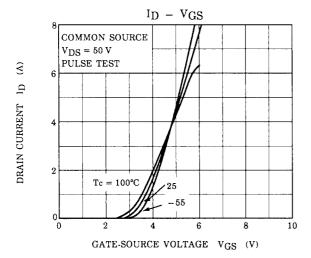
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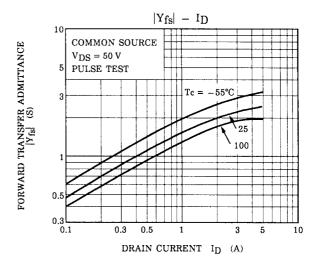
Marking

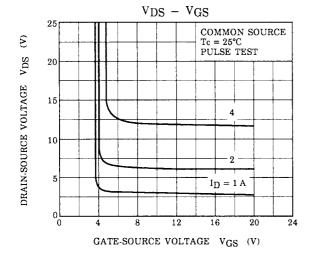


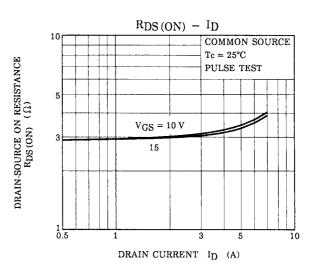




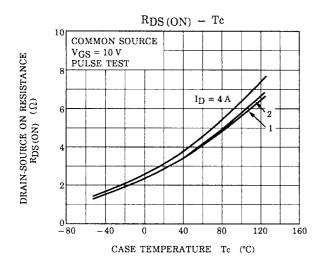


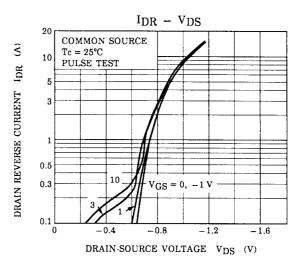


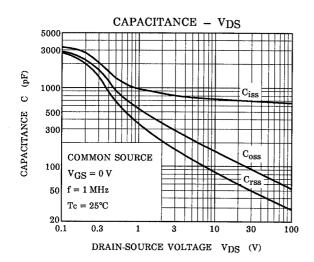


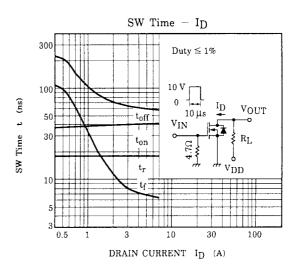


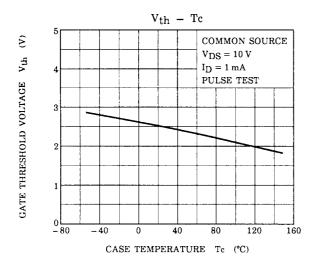
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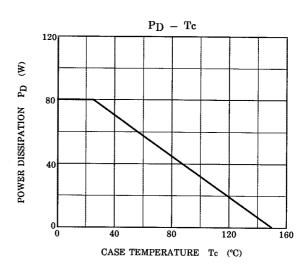




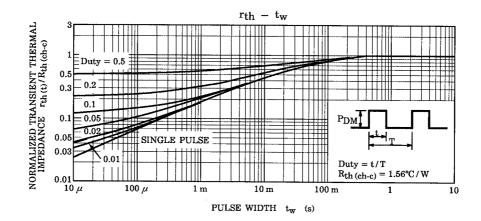


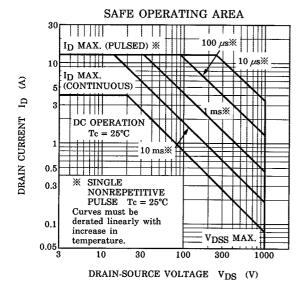






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